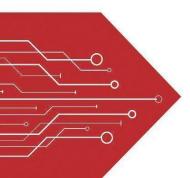
MSKSEMI















ESD

TVS

TSS

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GDT

PLED

Broduct data sheet

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SOD-123FL

FEATURES

- * Ideal for surface mount applications
- * Easy pick and place
- * Built-in strain relief
- * Fast switching speed

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Metallurgically bonded construction
- * Polarity: Color band denotes cathode end
- * Mounting position: Any

Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	P/N	FR10W F1	FR10W F2	FR103W F3	FR10W F4	FR105W F5	FR10W F6	FR10W F7	Units
	MARK	F1	F2	F3	F4	F5	F6	F7	
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at Ta = 65 °C	I _{F(AV)}	1.0					А		
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	30					Α		
Maximum Instantaneous Forward Voltage at 1 A	V _F	1.3					٧		
Maximum DC Reverse Current Ta = 25 °C at Rated DC Blocking Voltage Ta =125 °C	I _R	1 50					μA		
Maximum Reverse Recovery Time 1)	t _{rr}	150			250	500		ns	
Typical Junction Capacitance 2)	C _j	15					pF		
Operating and Storage Temperature Range	T_{j},T_{stg}	-55 ~ + 150				°C			

- 1) Measured with I_F = 0.5 A, I_R = 1 A, I_{rr} = 0.25 A
- 2) Measured at 1MHz and applied reverse voltage of 4V D.C



FIG.1-TYPICAL FORWARD

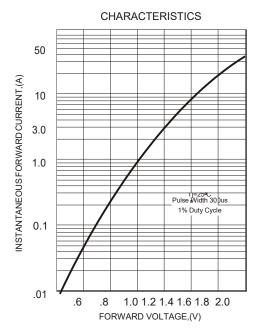
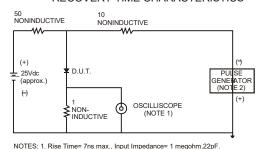


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., input impedance= 1 megonm.22p

2. Rise Time= 10ns max., Source Impedance= 50 ohms.

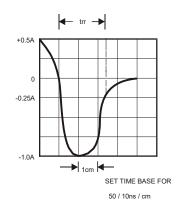


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

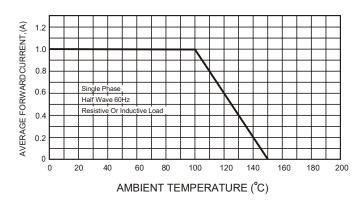


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

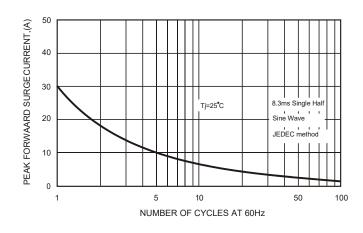
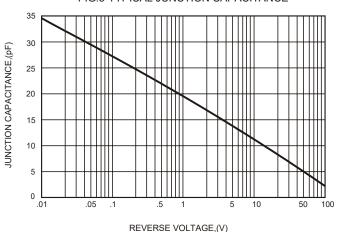
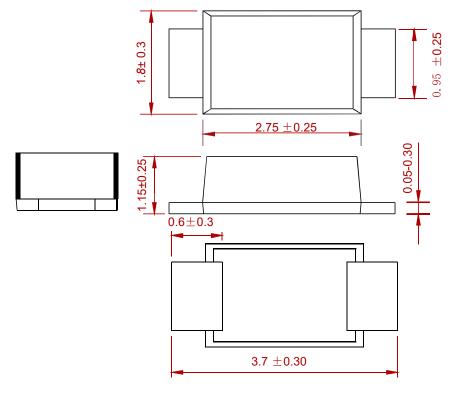


FIG.5-TYPICAL JUNCTION CAPACITANCE



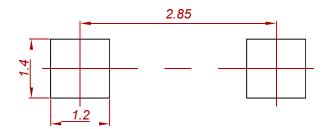
Semiconductor

PACKAGE MECHANICAL DATA



Dimensions in millimeters

Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
FR101W THRU FR107W	SOD-123FL	3000



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